

SSCN143GS7

NPN Type Digital Transistor (built-in resistors)

Features

vcc	VIN	Ю	R2/R1 Typ.		
50V	-5~+30V	100mA	10		

> Description

Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).

The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects. Only the on/off conditions need to be set for operation, making the device design easy.

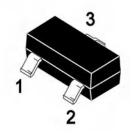
Applications

- Amplifying signal
- Electronic switch
- Oscillating circuit
- Variable resistance

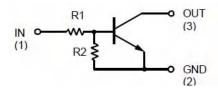
Ordering Information

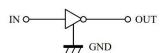
Device	Package	Shipping
SSCN143GS7	SOT-323	3000/Reel

Pin configuration



SOT-323





Circuit Diagram





ightharpoonup Absolute Maximum Ratings(T_A=25°C unless otherwise noted)

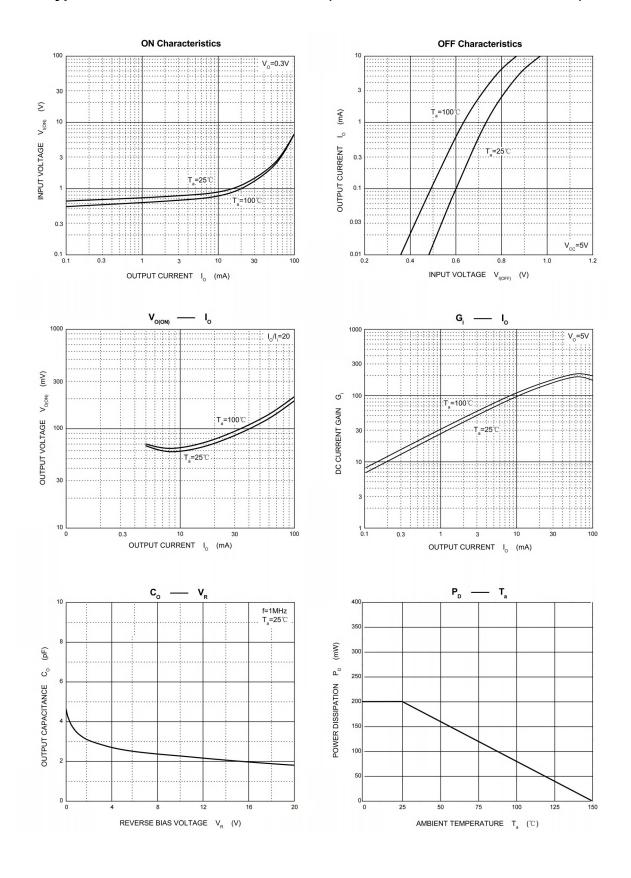
Parameter	Symbol	Value	Unit	
Supply Voltage	V _{CC}	50	V	
Input Voltage	V _{CN}	-5 to +30	V	
Output current	lo	100	mA	
Collector Power Dissipation	Pc	200	mW	
Junction Temperature	TJ	-55 to 150	$^{\circ}$	
Storage Temperature	T _{STG}	-55 to 150	$^{\circ}$ C	

➤ Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Input Valtage	V _{I(off)}	V _{CC} =5V , I _O =-100uA	0.5			V
Input Voltage	V _{I(on)}	V _{CC} =0.3V , I _O =5mA			1.3	V
Output Voltage	$V_{O(on)}$	I _O /I _I =-5mA/0.25mA		0.1	0.3	V
Input Current	I ₁	V _I =5V			1.8	mA
Output Current	I _{O(off)}	V _{CC} =-50V , V _I =0V			0.5	uA
DC Current Gain	G₁	V _O =5V , I _O =10mA	80			
Input Resistance	R ₁		3.29	4.7	6.11	ΚΩ
Resistance Ration	R ₂ /R ₁		8	10	12	ΚΩ
Transition Frequency	f⊤	V _{CE} =10V,I _E =5mA,f=100MHz		250		MHz



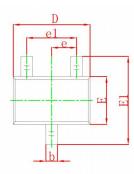
> Typical Performance Characteristics (T_A=25℃ unless otherwise noted)

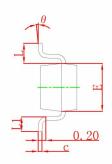


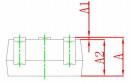


Package Information

SOT-323

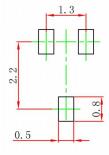






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650 TYP		0.026	TYP
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021	REF
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-323 Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
 2.General tolerance:±0.05mm.
 3.The pad layout is for reference purposes only.



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